

Total No. of Questions - [3]

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G.R. No.	

PAPER CODE V123-204 A(REG)

## MAY 2023 (INSEM+ ENDSEM) EXAM

F.Y. B. TECH. (SEMESTER - II)

COURSE NAME: ENGINEERING PHYSICS

**COURSE CODE: ES10204A** 

(PATTERN 2020)

Time: [2Hr]

[Max. Marks: 60]

- (\*) Instructions to candidates:
- 1) Figures to the right indicate full marks.
- 2) Use of scientific calculator is allowed
- 3) Use suitable data where ever required

Question	Question Description	Marks	CO	Blooms Taxonomy
No.			mapped	Level
Q.1	Solve the following  i) A vibration represented by a cosine function is a  (a) Random vibration (b) Aperiodic vibration (c) Simple Harmonic vibration (d) combination of random and periodic vibration	[2]	[1]	Remember
	ii) Starting from the expression for displacement for undamped oscillations $u(t) = Acos\omega_n t + Bsin\omega_n t$ , the velocity $v(t)$ is given by  (a) $-B\omega_n sin\omega_n t + A\omega_n cos\omega_n t$ (b) $-A\omega_n cos\omega_n t + B\omega_n sin\omega_n t$ (c) $-Asin\omega_n t + Bcos\omega_n t$ (d) $-A\omega_n sin\omega_n t + B\omega_n cos\omega_n t$	[2]	[1]	Understand
	iii) In viscously damped oscillations, which of the following statement is true?  (a) Velocity is proportional to the displacement (b) Damping is proportional to the velocity (c) There is no dissipation of energy (d) Amplitude remains constant	[2]	[1]	Remember
	iv) For a critically viscously damped free oscillation, the damped time period is (a) Finite and small (b) finite and large (c) infinite (d) indeterminate	[2]	[1]	Understand

C C 1 homorio	[2]	[1]	Understand
v) The complementary solution of forced harmonic oscillations with viscous damping corresponds to (a) Resonant state (b) The steady state (c) Undamped free	[2]	[1]	Onderstand
oscillation (d) damped free oscillation			
vi) For an underdamped free oscillation (viscously damped), which of the following statements is false  (a) $\omega_D$ is finite.	[2]	[1]	Analysis
(b) $T_D$ is finite.		İ	
<ul> <li>(c) There is oscillatory behaviour with the amplitude decreasing exponentially</li> <li>(d) ζ &gt; 1</li> </ul>			
vii) The logarithmic decrement for a viscously damped oscillation, if the amplitudes for 2 <sup>nd</sup> and 4 <sup>th</sup> oscillations are 10 cm and 2cm, respectively, is	[2]	[1]	Analysis
(a) e <sup>0.8</sup> (b) 0.008 (c) 0.08 (d) 0.80			
viii) The displacement of a simple harmonic motion is represented by the equation, $u(t) = (3.1 \text{ cm}) \sin(2.57t - 0.04)$ . The angular frequency and initial displacement are:	[2]	[1]	Analysis
(a) 2.75 rad/s, 0.0022cm (b) 2.57 rad/s, 0.0022cm (c) 2.75rad/s, -0.0022cm (d) 2.57rad/s, -0.124cm			
ix) In an n-type semiconductor, with decreased doping	[2]	[2]	Understand
concentrations, the Fermi			
level			
(a) shifts towards the conduction band	1		
(b) shifts towards the valence band		,	
(c) shifts towards the centre (d) none of the options			
x) The charge on a p-type semiconductor sample is	[2]	[2]	Understand
(a) positive (b) negative (c) neutral (d) none of these			
xi) Which of these statements regarding a p-n junction diod			
false?	[2]	[2]	Understand
(a) The depletion region is depleted of free charge carriers	1		
(b) The depletion layer consists of immobile positive charges on the n-side and immobile negative charges on the p side			·
(c) The depletion layer has no mobile electrons and holes (d) The depletion layer has free charges both holes and electrons			
xii) For p-type GaAs with a band gap of 1.424eV, if $E_{Fo}$ =0.5eV, then $E_{Fp}$ - $E_v$ is equal to	[2]	[2]	Analysis

	·····		
(a) 0.924eV (b) 0.212eV (c) 1.012eV (d) 1.212eV  xiii) For two samples A and B of n-type semiconductor having the same intrinsic carrier concentration, the doping concentration of donor impurities is 1×10 <sup>20</sup> m <sup>-3</sup> and 3×10 <sup>20</sup> m <sup>-3</sup> , respectively. If the hole concentration in sample A is	[2]	[2]	Analysis
$9\times10^{12}$ m <sup>-3</sup> , then the hole concentration in sample B is  (a) $3\times10^{12}$ m <sup>-3</sup> (b) $1\times10^{12}$ m <sup>-3</sup> (c) $27\times10^{12}$ m <sup>-3</sup> (d) $9\times10^{12}$ m  xiv) If the value of Fermi Dirac distribution function is 0.95 for T = 300K and given Boltzmann's constant $k = 8.6 \times 10^{-5}$ eV/K, then the value of E-E <sub>F</sub> is  (a) 0.076 eV	[2]	[2]	Analysis
<ul> <li>(b) 0.076 J</li> <li>(c) -0.076 eV</li> <li>(d) 0.05 eV</li> <li>xv) The value of gamma integral Γ (1/2) is √π then the value of Γ (9/2) is</li> <li>(a) (9×√π)/2</li> <li>(b) (945×√π)/32</li> <li>(c) (15×√π)/8</li> <li>(d) (105×√π)/16</li> </ul>	[2]	[2]	Analysis
Solve any three out of four  (a) Explain in brief what is meant by dispersion. If RMS material dispersion and RMS intermodal dispersion are 15 ns and 8 ns respectively, what will be its total dispersion and maximum speed at which digital bits can be sent.	[ <b>15</b> ]	[3]	Analysis
fractional refractive index is 0.001. Calculate numerical aperture, what is the max data speed that can be achieved for a length of 20 Km if we consider only RMS intermodal dispersion.	[5]	[3]	Analysis
factors responsible for attenuation.	[6]	[3]	Understand Analysis
	<ul> <li>(b) 0.212eV</li> <li>(c) 1.012eV</li> <li>(d) 1.212eV</li> <li>xiii) For two samples A and B of n-type semiconductor having the same intrinsic carrier concentration, the doping concentration of donor impurities is 1×10<sup>20</sup> m<sup>-3</sup> and 3×10<sup>20</sup> m<sup>-3</sup>, respectively. If the hole concentration in sample A is 9×10<sup>12</sup> m<sup>-3</sup>, then the hole concentration in sample B is <ul> <li>(a) 3×10<sup>12</sup> m<sup>-3</sup> (b) 1×10<sup>12</sup> m<sup>-3</sup> (c) 27×10<sup>12</sup> m<sup>-3</sup> (d) 9×10<sup>12</sup> m<sup>-3</sup></li> </ul> </li> <li>xiv) If the value of Fermi Dirac distribution function is 0.95 for T = 300K and given Boltzmann's constant k = 8.6 × 10<sup>-5</sup> eV/K, then the value of E-E<sub>F</sub> is <ul> <li>(a) 0.076 eV</li> <li>(b) 0.076 J</li> <li>(c) -0.076 eV</li> <li>(d) 0.05 eV</li> </ul> </li> <li>xv) The value of gamma integral Γ (1/2) is √π then the value of Γ (9/2) is <ul> <li>(a) (9×√π)/2</li> <li>(b) (945×√π)/32</li> <li>(c) (15×√π)/8</li> <li>(d) (105×√π)/16</li> </ul> </li> <li>Solve any three out of four <ul> <li>(a) Explain in brief what is meant by dispersion. If RMS material dispersion and RMS intermodal dispersion are 15 ns and 8 ns respectively, what will be its total dispersion and maximum speed at which digital bits can be sent.</li> <li>(b) If optical fibre has a core refractive index of 1.49 with fractional refractive index is 0.001. Calculate numerical aperture, what is the max data speed that can be achieved for a length of 20 Km if we consider only RMS intermodal dispersion.</li> <li>(c) What is attenuation in optical fibre. Explain in detail factors responsible for attenuation.</li> </ul> </li> <li>(d) A rules with a nower of 0.02 mW is launched into an optical fibre in the sum of the property of the prope</li></ul>	<ul> <li>(b) 0.212eV</li> <li>(c) 1.012eV</li> <li>(d) 1.212eV</li> <li>(d) 1.212eV</li> <li>(e) 1.012eV</li> <li>(d) 1.212eV</li> <li>(e) 1.012eV</li> <li>(d) 1.212eV</li> <li>(e) 1.012eV</li> <li>(d) 1.212eV</li> <li>(e) 1.012eV</li> <li>(f) 1.212eV</li> <li>(g) 1.212eV</li> <li>(h) 1.212eV</li> <li>(ii) 1.200 m<sup>-3</sup> and 3×10<sup>20</sup> m<sup>-3</sup> and 3×10<sup>20</sup> m<sup>-3</sup>, respectively. If the hole concentration in sample A is 9×10<sup>12</sup> m<sup>-3</sup>, then the hole concentration in sample B is (a) 3×10<sup>12</sup> m<sup>-3</sup> (b) 1×10<sup>12</sup> m<sup>-3</sup> (c) 27×10<sup>12</sup> m<sup>-3</sup> (d) 9×10<sup>12</sup> m</li> <li>(iii) 1.2 m<sup>-3</sup> (b) 1×10<sup>12</sup> m<sup>-3</sup> (c) 27×10<sup>12</sup> m<sup>-3</sup> (d) 9×10<sup>12</sup> m</li> <li>(iv) 1.2 fthe value of Fermi Dirac distribution function is 0.95 for T = 300K and given Boltzmann's constant k = 8.6 ×</li> <li>(iv) 1.2 eV/K, then the value of E-E<sub>F</sub> is</li> <li>(a) 0.076 eV</li> <li>(b) 0.076 J</li> <li>(c) -0.076 eV</li> <li>(d) 0.05 eV</li> <li>(e) (15×√π)/32</li> <li>(f) (15×√π)/16</li> <li>(g) (15×√π)/16</li> <li>(h) (945×√π)/16</li> <li>(iv) (15×√π)/16</li> <li>(iv) (15√π)/16</li> <li>(iv) (15√π)/16</li> <li>(iv) (15√m)/16</li> <li>(iv) (15√m)/1</li></ul>	<ul> <li>(b) 0.212eV</li> <li>(c) 1.012eV</li> <li>(d) 1.212eV</li> <li>xiii) For two samples A and B of n-type semiconductor having the same intrinsic carrier concentration, the doping concentration of donor impurities is 1×10<sup>20</sup> m<sup>3</sup> and 3×10<sup>20</sup> m<sup>3</sup>, respectively. If the hole concentration in sample A is 9×10<sup>12</sup> m<sup>3</sup>, then the hole concentration in sample B is <ul> <li>(a) 3×10<sup>12</sup> m<sup>3</sup> (b) 1×10<sup>12</sup> m<sup>3</sup> (c) 27×10<sup>12</sup> m<sup>3</sup> (d) 9×10<sup>12</sup> m</li> </ul> </li> <li>xiv) If the value of Fermi Dirac distribution function is 0.95 for T = 300K and given Boltzmann's constant k = 8.6 ×</li> <li>10<sup>-5</sup> eV/K, then the value of E-E<sub>F</sub> is</li> <li>(a) 0.076 eV</li> <li>(b) 0.076 J</li> <li>(c) -0.076 eV</li> <li>(d) 0.05 eV</li> <li>xv) The value of gamma integral Γ (1/2) is √π then the value of Γ (9/2) is</li> <li>(a) (9×√π)/2</li> <li>(b) (945×√π)/32</li> <li>(c) (15×√π)/8</li> <li>(d) (105×√π)/16</li> </ul> <li>Solve any three out of four <ul> <li>(a) Explain in brief what is meant by dispersion. If RMS material dispersion and RMS intermodal dispersion are 15 ns and 8 ns respectively, what will be its total dispersion and maximum speed at which digital bits can be sent.</li> <li>(b) If optical fibre has a core refractive index of 1.49 with fractional refractive index is 0.001. Calculate numerical aperture, what is the max data speed that can be achieved for a length of 20 Km if we consider only RMS intermodal dispersion.</li> <li>(c) What is attenuation in optical fibre. Explain in detail factors responsible for attenuation.</li> <li>(b) A rules with a power of 0.02 mW is launched into an optical fibre and only an optical fibre.</li> </ul></li>

	the distance after which the power drops to 0.0002mW, which is detection light of the light sensor used to detect the signal at the end of this unbroken fibre. If 10 repeaters are used to extend the distance over which the signal can be transmitted then what is the total distance achieved.			
Q.3	Solve any three out of four	[15]		
	(a) What is meant by Rayleigh range, drive its relation with the help of a neat labeled diagram.	[5]	[4]	Understand
	(b) An Argon Laser has a wavelength of 514 nm with a width of gain curve about 4 GHz. The length of the optical cavity is 20 cm. Calculate the following:	[5]	[4]	Analysis
	<ol> <li>mode number m</li> <li>peak frequency</li> <li>width of the gain curve in terms of wavelength (Δλ)</li> <li>mode separation frequency v<sub>ms</sub></li> <li>how many modes are allowed in the width of the gain curve.</li> </ol>			
	(c) Explain the phenomena of absorption, spontaneous emission and stimulated emission of light by matter with the help of neat labelled diagrams.	[5]	[4]	Understand
	(d)With a neat labelled diagram explain the principle, construction and working of Single Hetero Junction Laser Diode.	[5]	[4]	Understand

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